

RoHS

COMPLIANT

HALOGEN

FREE Available

Vishay Siliconix

N-Channel Reduced Q_g , Fast Switching MOSFET

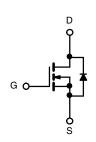
PRODUCT SUMMARY				
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)		
30	0.0032 at V _{GS} = 10 V	25		
30	0.0036 at V _{GS} = 4.5 V	22		

FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- Extremely Low Q_{gd} for Switching Losses Improvement
- TrenchFET[®] Gen II Power MOSFET
- 100 % Rg Tested
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- Low-Side DC/DC Conversion
 Notebook, Server, VRM Module
- Fixed Telecom



N-Channel MOSFET

	SO-8	
S 1 S 2 S 3 G 4		8 D 7 D 6 D 5 D
	Top View	-

Ordering Information: Si4368DY-T1-E3 (Lead (Pb)-free) Si4368DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS	(·A,				
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	30		V
Gate-Source Voltage		V _{GS}	± 12		
Continuous Durin Consent (T 150 °C)	T _A = 25 °C	– I _D	25	17	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		20	13	
Pulsed Drain Current (10 µs Pulse Width)		I _{DM}	70		А
Continuous Source Current (Diode Conduction) ^a		ا _S	2.9	1.3	
Avalanch Current	L = 0.1 mH	I _{AS}	50		
Maximum Power Dissipation ^a	T _A = 25 °C	D	3.5	1.6	W
Maximum Power Dissipation	T _A = 70 °C	- P _D	2.2	1	
Operating Junction and Storage Temperature Range		T _J , T _{stq}	- 55	to 150	°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^a	t ≤ 10 s	R _{thJA}	29	35	°C/W	
Maximum Sunction-to-Amblent*	Steady State		67	80		
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	13	16		

Notes:

a. Surface mounted on 1" x 1" FR4 board.

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \ \mu A$	0.6		1.8	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 12 V$			± 100	nA	
Zara Cata Valtaga Drain Current	1	$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1		
Zero Gate Voltage Drain Current	DSS	V _{DS} = 30 V, V _{GS} = 0 V, T _J = 55 °C			5	μA	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α	
Drain-Source On-State Resistance ^a		V _{GS} = 10 V, I _D = 25 A		0.0026	0.0032	Ω	
Drain-Source On-State Resistance"	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 22 \text{ A}$		0.0029	0.0036		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 25 A		150		S	
Diode Forward Voltage ^a	V _{SD}	$I_{S} = 2.9 \text{ A}, V_{GS} = 0 \text{ V}$		0.66	1.1	V	
Dynamic ^b							
Input Capacitance	C _{iss}			8340			
Output Capacitance	C _{oss}	V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz		850		pF	
Reverse Transfer Capacitance	C _{rss}			355			
Total Gate Charge	Qg			53	80		
Gate-Source Charge	Q _{gs}	V_{DS} = 15 V, V_{GS} = 4.5 V, I_{D} = 20 A		17.5		nC	
Gate-Drain Charge	Q _{gd}			6.5]	
Gate Resistance	R _g	f = 1 MHz	0.8	1.2	1.8	Ω	
Turn-On Delay Time	t _{d(on)}			25	38		
Rise Time	t _r	$V_{DD} = 15 \text{ V}, \text{ R}_{L} = 15 \Omega$		20	30]	
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 6 \Omega$		172	260	ns	
Fall Time	t _f			41	62		
Source-Drain Reverse Recovery Time	t _{rr}	I _E = 2.9 A, dl/dt = 100 A/μs		42	60		

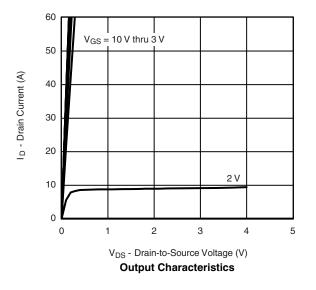
Notes:

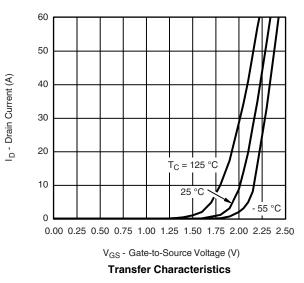
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



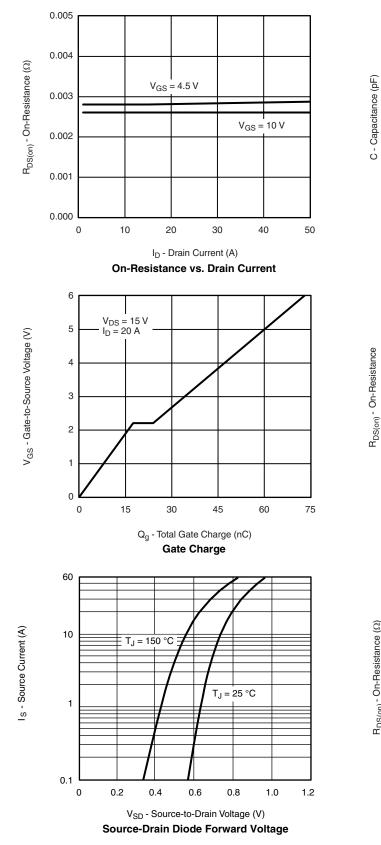


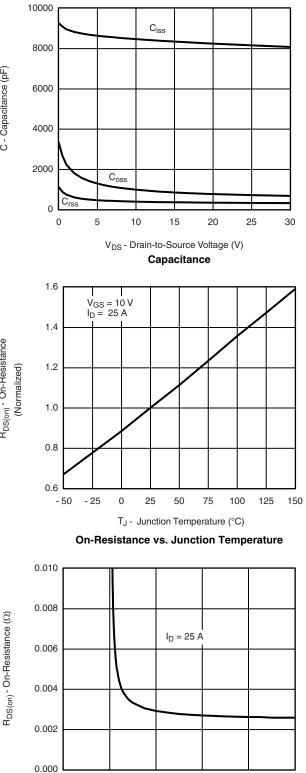


Si4368DY

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





V_{GS} - Gate-to-Source Voltage (V) On-Resistance vs. Gate-to-Source Voltage

6

4

0

2

Document Number: 72704 S11-0209-Rev. D, 14-Feb-11 10

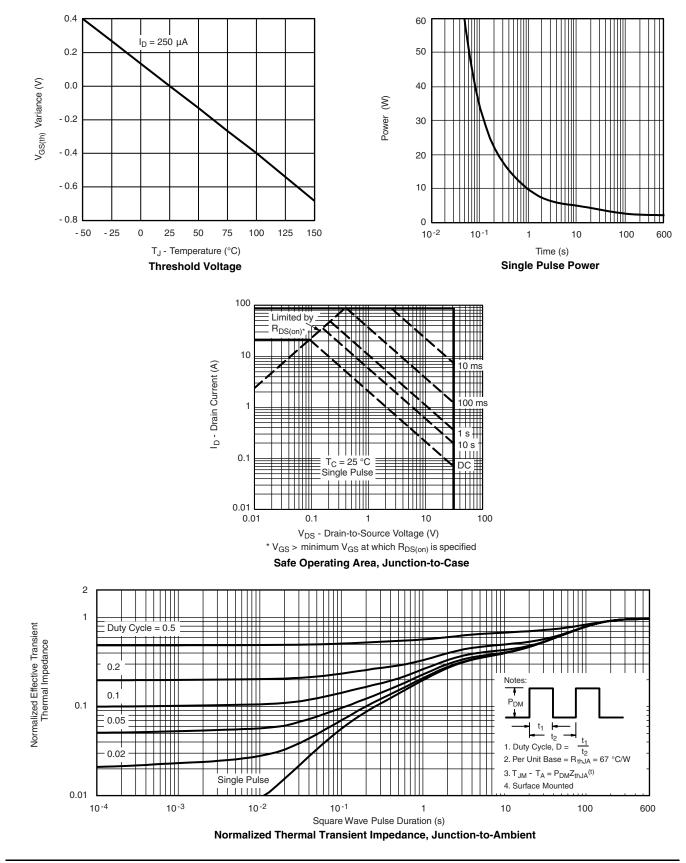
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

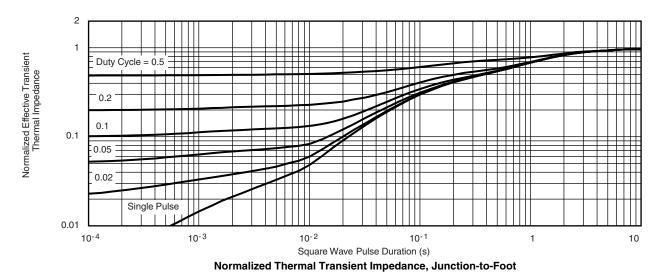




Si4368DY

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72704.



Package Information

Vishay Siliconix

SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012





	MILLIM	IETERS	TERS INC			
DIM	Min	Мах	Min	Max		
A	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
E	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498						

Application Note 826

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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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